

DESCRIPTION

The IS181 series of optocoupler consists of an infrared light emitting diode optically coupled to an NPN silicon photo transistor in a space efficient Mini Flat Package.

FEATURES

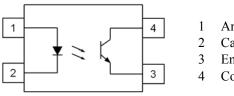
- Low Profile Package .
- AC Isolation Voltage 3750V_{RMS}
- **CTR Selections Available** .
- Wide Operating Temperature Range . -55°C to +110°C
- Lead Free and RoHS Compliant
- UL File E91231 model "FPT1" and "FPT2"

APPLICATIONS

- **Computer Terminals** •
- Industrial System Controllers
- **Measuring Instruments** .
- Signal Transmission between Systems of **Different Potentials and Impedance**

ORDER INFORMATION

Available in Tape and Reel with 3000 pieces per reel



- Anode
- Cathode
- Emitter
- Collector

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Stresses exceeding the absolute maximum ratings can cause permanent damage to the device. Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

Input

Forward Current	50mA
Reverse Voltage	6V
Power dissipation	70mW

Output

Collector to Emitter Voltage BV_{CEO}	80V
Emitter to Collector Voltage BV_{ECO}	6V
Collector Current Power Dissipation	50mA 150mW

Total Package

Isolation Voltage	$3750V_{RMS}$
Total Power Dissipation	170mW
Operating Temperature	-55 to 110 °C
Storage Temperature	-55 to 150 °C
Lead Soldering Temperature (10s)	260°C

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise specified)

INPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward Voltage	\mathbf{V}_{F}	$I_F = 20 m A$		1.2	1.4	V
Reverse Current	I _R	$V_R = 4V$			10	μA
Terminal Capacitance	Ct	V = 0V, f = 1KHz		30	250	pF

OUTPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector-Emitter Breakdown Voltage	BV _{CEO}	$I_{\rm C} = 0.1 {\rm mA}, I_{\rm F} = 0 {\rm mA}$ 80				V
Emitter-Collector Breakdown Voltage	BV _{ECO}	$I_E = 10 \mu A$, $I_F = 0 m A$	6			V
Collector-Emitter Dark Current	I _{CEO}	$V_{CE} = 20V, I_F = 0mA$			100	nA

COUPLED

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Current Transfer Ratio	CTR	$I_F = 5mA$, $V_{CE} = 5V$	50		600	%
		Optional CTR Grades IS181A IS181B IS181C IS181D IS181GR IS181GB	80 130 200 300 100 100		$160 \\ 260 \\ 400 \\ 600 \\ 300 \\ 600$	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	$I_{\rm F} = 20 {\rm mA}, I_{\rm C} = 1 {\rm mA}$			0.2	V
Floating Capacitance	$C_{\rm f}$	V = 0V, f = 1MHz		0.6	1	pF
Output Rise Time	t _r	$V_{CE} = 2V$, Ic = 2mA, $R_L = 100\Omega$		4	18	μs
Output Fall Time	$t_{\rm f}$	$V_{CE} = 2V$, Ic = 2mA, $R_L = 100\Omega$		3	18	μs

ISOLATION

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Insulation Voltage	V _{ISO}	RH = 40% to 60%, t = 1 min,	3750			V
Input - Output Resistance	R _{I-O}	$V_{I-O} = 500 VDC$	5x10 ¹⁰			Ω



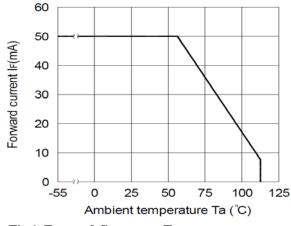


Fig 1 Forward Current vs T_A

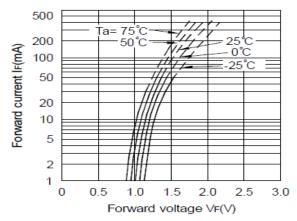
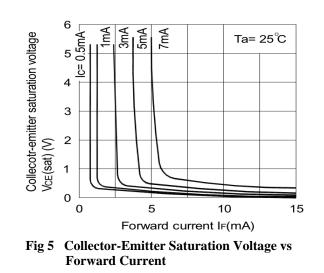


Fig 3 Forward Current vs Forward Voltage



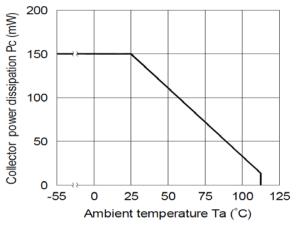


Fig 2 Collector Power Dissipation vs T_A

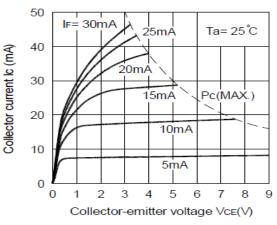


Fig 4 Collector Current vs Collector-Emitter Voltage

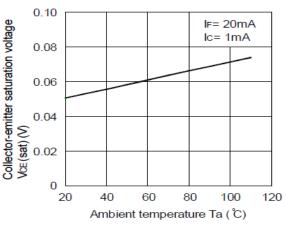
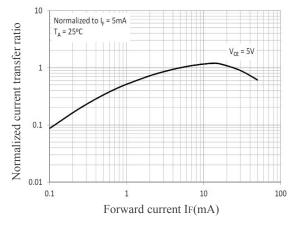
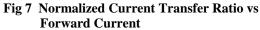


Fig 6 Collector-Emitter Saturation Voltage vs T_A







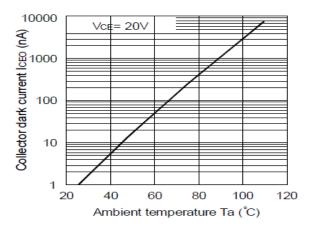
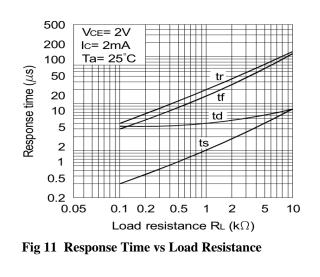


Fig 9 Collector Dark Current vs T_A



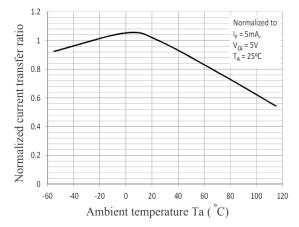


Fig 8 Normalized Current Transfer Ratio vs T_A

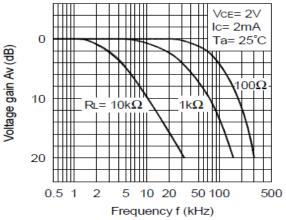
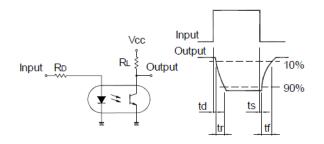


Fig 10 Frequency response

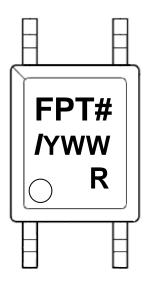




ORDER INFORMATION

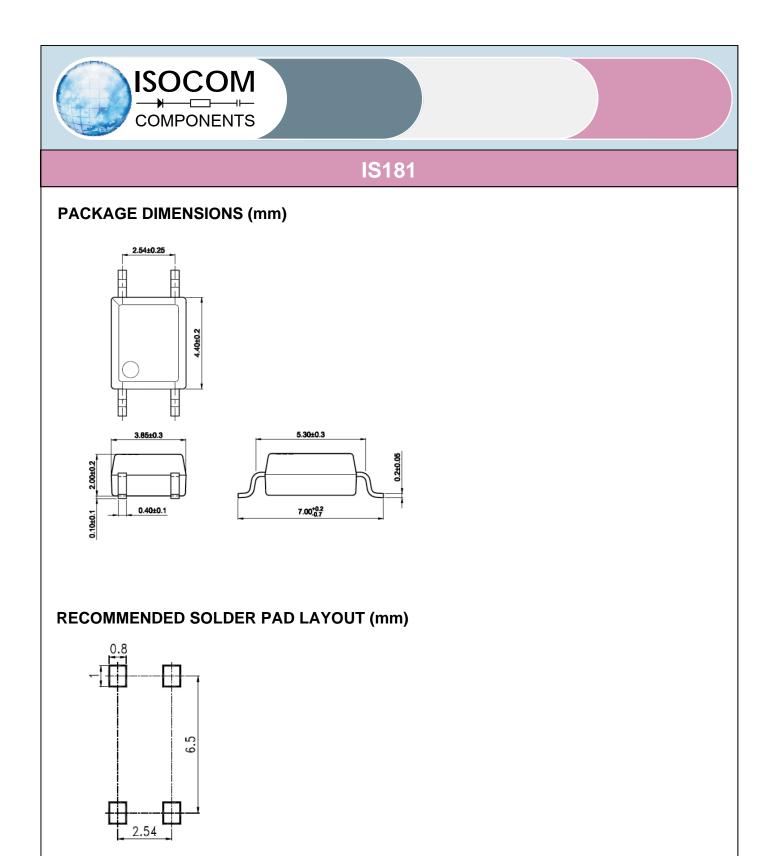
	IS181					
After PN	PN	Description	Packing quantity			
None	IS181	Surface Mount Tape & Reel	3000 pcs per reel			
	IS181A, IS181B, IS181C, IS181D, IS181GR, IS181GB	Surface Mount Tape & Reel	3000 pcs per reel			

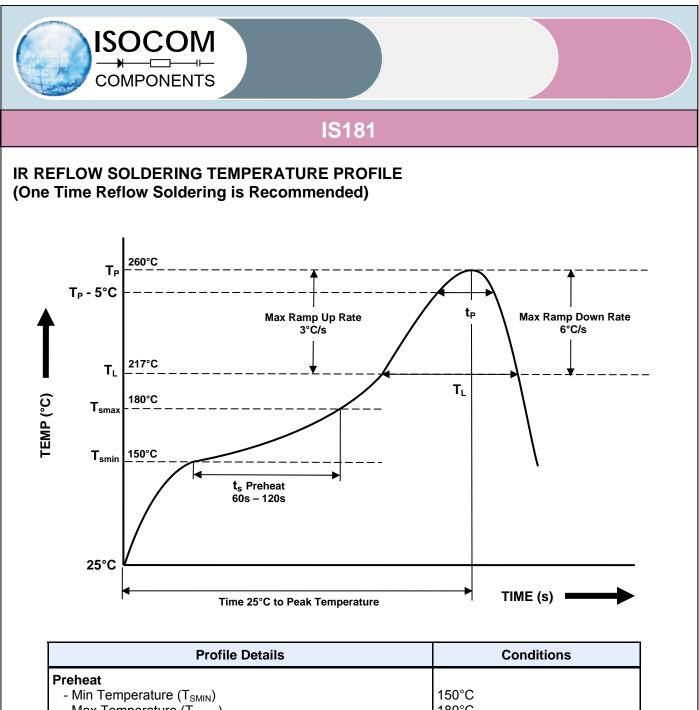
DEVICE MARKING



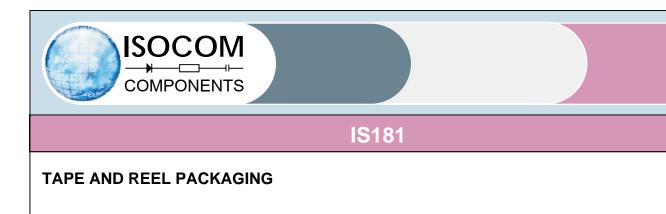
FPT#	denotes Device Part Number where "#" is internal control number
	which can be "1" or '2"

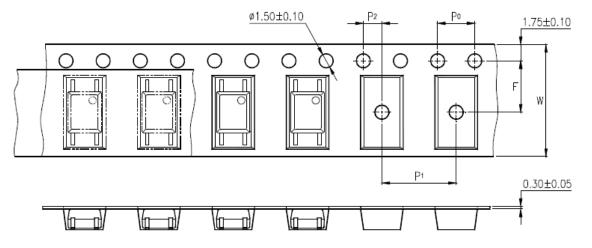
- I denotes Isocom
- Y denotes 1 digit Year code
- WW denotes 2 digit Week code
- R denotes CTR Grade





- Min Temperature (T _{SMIN}) - Max Temperature (T _{SMAX}) - Time T _{SMIN} to T _{SMAX} (t _s)	150°C 180°C 60s - 120s
	260°C 217°C 20s 60s 3°C/s max 3 - 6°C/s
Average Ramp Up Rate (T_{smax} to T_P)	3°C/s max
Time 25°C to Peak Temperature	8 minutes max





Description	Symbol	Dimension mm (inch)
Tape Width	W	12 ± 0.3 (0.47)
Pitch of Sprocket Holes	Po	4 ± 0.1 (0.15)
Distance of Comportment to Corrected Lieles	F	5.5 ± 0.1 (0.217)
Distance of Compartment to Sprocket Holes	P ₂	2 ± 0.1 (0.079)
Distance of Compartment to Compartment	P ₁	8 ± 0.1 (0.315)



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- For equipment/application where high reliability or safety is required, such as space applications, nuclear power control equipment, medical equipment, etc., please contact our sales representatives.

- When requiring a device for any "specific" application, please contact our sales for advice.

- The contents described herein are subject to change without prior notice.
- Do not immerse device body in solder paste.



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